

## PNP POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/545

### Devices

2N5151  
2N5151L

2N5153  
2N5153L

### Qualified Level

JAN  
JANTX  
JANTXV

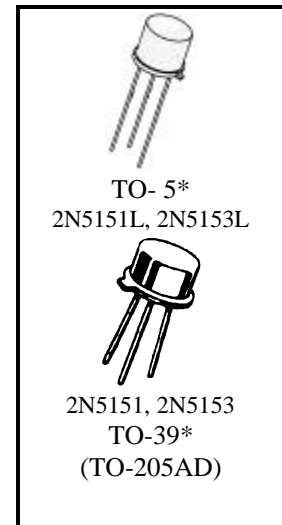
### MAXIMUM RATINGS

| Ratings                               | Symbol         | All Units                    | Units       |
|---------------------------------------|----------------|------------------------------|-------------|
| Collector-Emitter Voltage             | $V_{CEO}$      | 80                           | Vdc         |
| Collector-Base Voltage                | $V_{CBO}$      | 100                          | Vdc         |
| Emitter-Base Voltage                  | $V_{EBO}$      | 5.5                          | Vdc         |
| Collector Current                     | $I_C^{(3,4)}$  | 2.0                          | Adc         |
| Total Power Dissipation               | $P_T$          | @ $T_A = +25^{\circ}C^{(1)}$ | 1.0         |
|                                       |                | @ $T_C = +25^{\circ}C^{(2)}$ | 11.8        |
| Operating & Storage Temperature Range | $T_j, T_{stg}$ | -65 to +200                  | $^{\circ}C$ |

### THERMAL CHARACTERISTICS

| Characteristics                      | Symbol          | Max. | Unit          |
|--------------------------------------|-----------------|------|---------------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 15   | $^{\circ}C/W$ |

- 1) Derate linearly 5.7 mW/ $^{\circ}C$  for  $T_A > +25^{\circ}C$
- 2) Derate linearly 66.7 mW/ $^{\circ}C$  for  $T_C > +25^{\circ}C$
- 3) Derate linearly 6.67 mW/ $^{\circ}C$  for  $T_A > +25^{\circ}C$
- 4) Derate linearly 80 mW/ $^{\circ}C$  for  $T_C > +25^{\circ}C$



\*See appendix A for package outline

### ELECTRICAL CHARACTERISTICS ( $T_C = 25^{\circ}C$ unless otherwise noted)

| Characteristics | Symbol | Min. | Max. | Unit |
|-----------------|--------|------|------|------|
|-----------------|--------|------|------|------|

### OFF CHARACTERISTICS

|   |               |    |     |                 |
|---|---------------|----|-----|-----------------|
| Collector-Emitter Breakdown Voltage<br>$I_C = 100 \text{ mAdc}, I_B = 0$  | $V_{(BR)CEO}$ | 80 |     | Vdc             |
| Emitter-Base Cutoff Current<br>$V_{EB} = 4.0 \text{ Vdc}, I_C = 0$<br>$V_{EB} = 5.5 \text{ Vdc}, I_C = 0$           | $I_{EBO}$     |    | 1.0 | $\mu\text{Adc}$ |
|   |               |    | 1.0 | mAdc            |
| Collector-Emitter Cutoff Current<br>$V_{CE} = 60 \text{ Vdc}, V_{BE} = 0$<br>$V_{CE} = 100 \text{ Vdc}, V_{BE} = 0$ | $I_{CES}$     |    | 1.0 | $\mu\text{Adc}$ |
|   |               |    | 1.0 | mAdc            |
| Collector-Base Cutoff Current<br>$V_{CE} = 40 \text{ Vdc}, I_B = 0$   | $I_{CEO}$     |    | 50  | $\mu\text{Adc}$ |

## 2N5151, 2N5153 JAN SERIES

### ELECTRICAL CHARACTERISTICS (con't)

| Characteristics  | Symbol           | Min.     | Max.        | Unit |
|--|------------------|----------|-------------|------|
| <b>DC CHARACTERISTICS</b>  |                  |          |             |      |
| Forward Current Transfer Ratio<br>$I_C = 50 \text{ mA dc}, V_{CE} = 5 \text{ V dc}$  | 2N5151<br>2N5153 | 20<br>50 |             |      |
| $I_C = 2.5 \text{ A dc}, V_{CE} = 5 \text{ V dc}$  | 2N5151<br>2N5153 | 30<br>70 | 90<br>200   |      |
| $I_C = 5 \text{ A dc}, V_{CE} = 5 \text{ V dc}$  | 2N5151<br>2N5153 | 20<br>40 |             |      |
| Collector-Emitter Saturation Voltage<br>$I_C = 2.5 \text{ A dc}, I_B = 250 \text{ A dc}$<br>$I_C = 5 \text{ A dc}, I_B = 500 \text{ A dc}$ | $V_{CE(sat)}$    |          | 0.75<br>1.5 | Vdc  |
| Base-Emitter Voltage nonsaturated<br>$V_{CE} = 5 \text{ V dc}, I_C = 2.5 \text{ A dc}$   | $V_{BE}$         |          | 1.45        | Vdc  |
| Base-Emitter Saturation Voltage<br>$I_C = 2.5 \text{ A dc}, I_B = 250 \text{ mA dc}$<br>$I_C = 5 \text{ A dc}, I_B = 500 \text{ mA dc}$    | $V_{BE(sat)}$    |          | 1.45<br>2.2 | Vdc  |

### DYNAMIC CHARACTERISTICS

|   |            |          |     |    |
|---|------------|----------|-----|----|
| Magnitude of Common Emitter Small-Signal Short Circuit Forward-Current Transfer Ratio<br>$I_C = 500 \text{ mA dc}, V_{CE} = 5 \text{ V dc}, f = 10 \text{ MHz}$ | $ h_{fe} $ | 6<br>7   |     |    |
| Common-Emitter Small-Signal Short-Circuit Forward-Current Transfer Ratio<br>$I_C = 100 \text{ mA dc}, V_{CE} = 5 \text{ V dc}, f = 1 \text{ kHz}$               | $h_{fe}$   | 20<br>50 |     |    |
| Output Capacitance<br>$V_{CB} = 10 \text{ V dc}, I_E = 0, f = 1.0 \text{ MHz}$  | $C_{obo}$  |          | 250 | pF |

### SWITCHING CHARACTERISTICS

|  |           |  |     |               |
|--|-----------|--|-----|---------------|
| Turn-On Time<br>$I_C = 5 \text{ A dc}, I_{B1} = 500 \text{ mA dc}$ | $t_{on}$  |  | 0.5 | $\mu\text{s}$ |
| Turn-Off Time<br>$R_L = 6\Omega$                                   | $t_{off}$ |  | 1.5 | $\mu\text{s}$ |
| Storage Time<br>$I_{B2} = -500 \text{ mA dc}$                      | $t_s$     |  | 1.4 | $\mu\text{s}$ |
| Fall Time<br>$V_{BE(OFF)} = 3.7 \text{ V dc}$                      | $t_f$     |  | 0.5 | $\mu\text{s}$ |

### SAFE OPERATING AREA

|  |
|--|
| DC Tests<br>$T_C = +25^\circ\text{C}, 1 \text{ Cycle}, t_p = 1.0 \text{ s}$<br><b>Test 1</b><br>$V_{CE} = 5.8 \text{ V dc}, I_C = 2.0 \text{ A dc}$<br><b>Test 2</b><br>$V_{CE} = 32 \text{ V dc}, I_C = 340 \text{ mA dc}$<br><b>Test 3</b><br>$V_{CE} = 80 \text{ V dc}, I_C = 20 \text{ mA dc}$ |
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